

GaAs IC 2 Watt High Linearity SPDT Switch DC–2 GHz



AS359-62

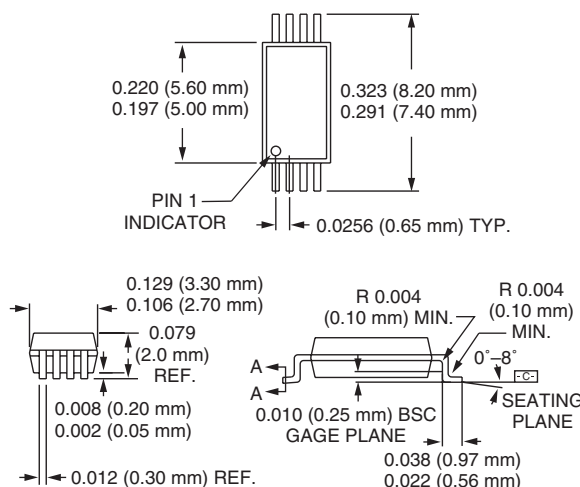
Features

- High Linearity (55 dBm IP3 @ 0.9 GHz)
- Low Insertion Loss (0.35 dB @ 0.9 GHz)
- Antenna Changeover and T/R Cellular Switch

Description

The AS359-62 is a GaAs FET IC SPDT switch in an SSOP-8 plastic package. The switch has been designed for use where extremely high linearity and low insertion loss are required. It can be controlled with positive, negative or a combination of both voltages. Some standard implementations include antenna changeover, T/R and diversity switching over 2 W. The AS359-62 switch can be used in many analog and digital wireless communication systems including cellular, GSM and DECT applications.

SSOP-8



Electrical Specifications at 25°C (0, -5 V)

Parameter ¹	Frequency ²	Min.	Typ.	Max.	Unit
Insertion Loss ³	DC–0.5 GHz		0.3	0.4	dB
	DC–1.0 GHz		0.4	0.6	dB
	DC–2.0 GHz		1.0	1.2	dB
Isolation	DC–0.5 GHz	20	23		dB
	DC–1.0 GHz	15	17		dB
	DC–2.0 GHz	8	10		dB
VSWR ⁴	DC–0.5 GHz		1.3:1	1.4:1	
	DC–2.0 GHz		1.3:1	1.8:1	

Operating Characteristics at 25°C (0, -5 V)

Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics ⁵	Rise, Fall (10/90% or 90/10% RF)			60		ns
	On, Off (50% CTL to 90/10% RF)			100		ns
	Video Feedthru			50		mV
Input Power for 1 dB Compression	0/-5 V	0.9 GHz		+35		dBm
	0/-8 V	0.9 GHz		+37		dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power +10 dBm	0.9 GHz		+55		dBm
Reverse Intermodulation Products (RIM)	T _X Tone @ +30 dBm, 830 MHz					
	Interference Tone @ +10 dBm, 785 MHz					
	V _{High} 0/-5 V V _{High} 0/-8.5 V			-55 -80		dBm dBm
Control Voltages	V _{Low} = 0 to -0.2 V @ 20 µA Max.					
	V _{High} = -3 V @ 50 µA to -9 V @ 200 µA Max.					

1. All measurements made in a 50 Ω system, unless otherwise specified.

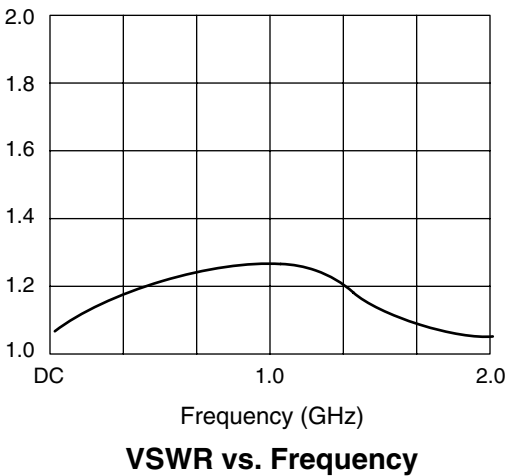
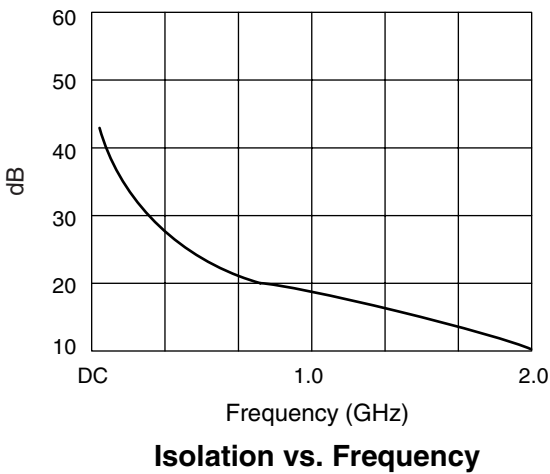
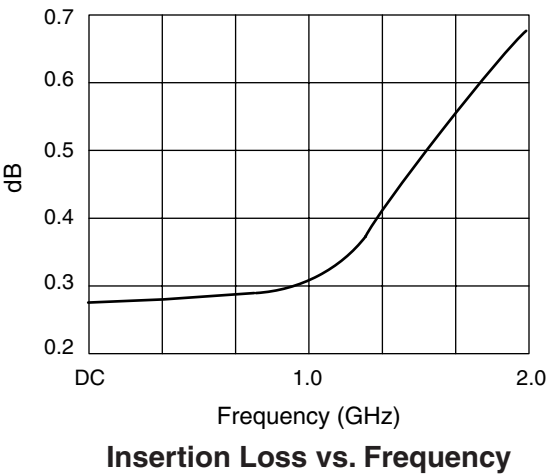
2. DC = 300 kHz.

3. Insertion loss changes by 0.003 dB/°C.

4. Insertion loss state.

5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

Typical Performance Data (0, -5 V)



Truth Table

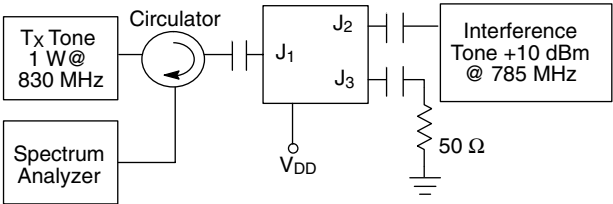
V ₁	V ₂	J ₁ –J ₂	J ₁ –J ₃
0	V _{High}	Isolation	Insertion Loss
V _{High}	0	Insertion Loss	Isolation

Refer to application note for positive voltage operation.

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	6 W Max. > 900 MHz, 0 V/-8 V Control
Control Voltage	+0.2 V, -10 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Θ _{JC}	25°C/W

Reverse Intermodulation Products (RIM) Setup



Pin Out

